



DST3906DJ

## **DUAL 40V PNP SURFACE MOUNT TRANSISTOR**

## Features

- V<sub>CEO</sub> = -40V
- I<sub>C</sub> = -200mA
- Epitaxial Planar Die Construction
- Ideally Suited for Automated Assembly Processes
- Lead, Halogen and Antimony Free, RoHS Compliant (Note 1)
- "Green" Device (Note 2)
- Ultra Small Package

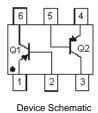
## **Mechanical Data**

- Case: SOT-963
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Weight: 0.0027 grams (approximate)

SOT-963



Top View



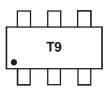
**Ordering Information** 

Device	Packaging	Shipping
DST3906DJ-7	SOT-963	10,000/Tape & Reel

Notes: 1. No purposefully added lead. Halogen and Antimony Free.

2. Diodes Inc's "Green" Policy can be found on our website at http://www.diodes.com

## **Marking Information**



T9 = Product Type Marking Code



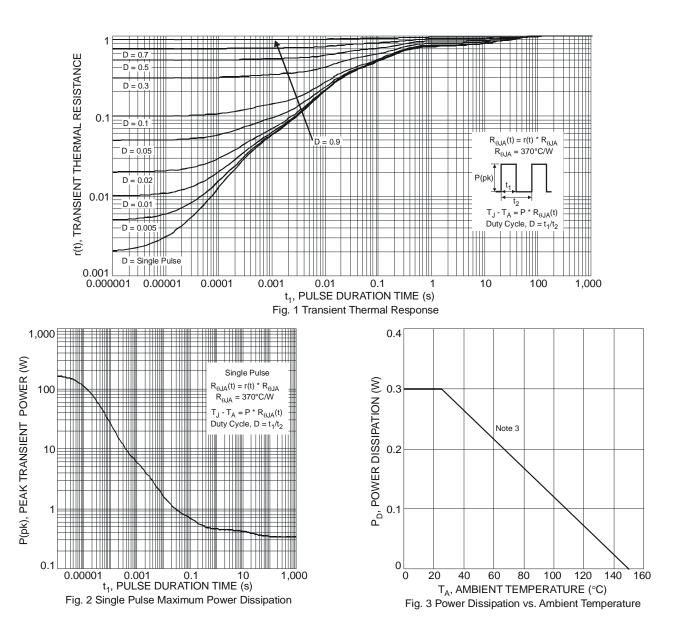
## **Maximum Ratings** $@T_A = 25^{\circ}C$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-40	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-40	V
Emitter-Base Voltage	V <sub>EBO</sub>	-5.0	V
Collector Current - Continuous (Note 3)	lc	-200	mA

## **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3)	PD	300	mW
Thermal Resistance, Junction to Ambient (Note 3)	R <sub>0JA</sub>	417	°C/W
Operating and Storage Temperature Range	TJ, T <sub>STG</sub>	-55 to +150	°C

Notes: 3. Device mounted on FR-4 PCB with minimum recommended pad layout.



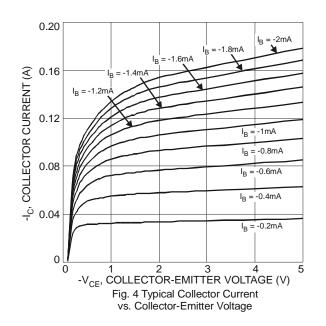


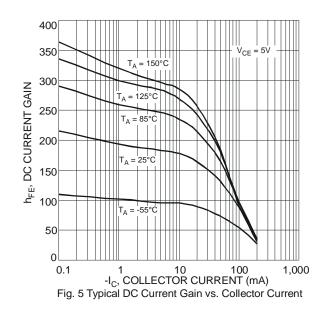
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# **Electrical Characteristics** $@T_A = 25^{\circ}C$ unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition	
OFF CHARACTERISTICS	Symbol	IVIIII	IVIAX	Unit		
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	-40	_	V	$I_{\rm C} = -10 \mu A, I_{\rm E} = 0$	
Collector-Emitter Breakdown Voltage (Note 4)	V(BR)CEO	-40	_	V	$I_{\rm C} = -1.0 \text{mA}, I_{\rm B} = 0$	
Emitter-Base Breakdown Voltage	V(BR)EBO	-5.0	_	V	$I_{\rm F} = -10\mu A$ , $I_{\rm C} = 0$	
	ICEX	_	-50	nA	$V_{CE} = -30V, V_{EB(OFF)} = -3.0V$	
Collector Cutoff Current	I <sub>CBO</sub>	_	-50	nA	$V_{CB} = -30V, I_E = 0$	
Base Cutoff Current	I <sub>BL</sub>	_	-50	nA	$V_{CE} = -30V, V_{EB(OFF)} = -3.0V$	
ON CHARACTERISTICS (Note 4)	·DL					
DC Current Gain	h <sub>FE</sub>	60 80 100 60 30	 300 	_	$\begin{split} I_{C} &= -100 \mu A, \ V_{CE} &= -1.0V \\ I_{C} &= -1.0mA, \ V_{CE} &= -1.0V \\ I_{C} &= -10mA, \ V_{CE} &= -1.0V \\ I_{C} &= -50mA, \ V_{CE} &= -1.0V \\ I_{C} &= -100mA, \ V_{CE} &= -1.0V \end{split}$	
Collector-Emitter Saturation Voltage	V <sub>CE</sub> (SAT)	_	-0.25 -0.40	V	I <sub>C</sub> = -10mA, I <sub>B</sub> = -1.0mA I <sub>C</sub> = -50mA, I <sub>B</sub> = -5.0mA	
Base-Emitter Saturation Voltage	V <sub>BE(SAT)</sub>	-0.65	-0.85 -0.95	V	I <sub>C</sub> = -10mA, I <sub>B</sub> = -1.0mA I <sub>C</sub> = -50mA, I <sub>B</sub> = -5.0mA	
SMALL SIGNAL CHARACTERISTICS						
Output Capacitance	C <sub>obo</sub>		4.5	pF	$V_{CB} = -5.0V, f = 1.0MHz, I_E = 0$	
Input Capacitance	Cibo		10	pF	$V_{EB} = -0.5V$ , f = 1.0MHz, I <sub>C</sub> = 0	
Input Impedance	h <sub>ie</sub>	2.0	12	kΩ		
Voltage Feedback Ratio	h <sub>re</sub>	0.1	10	x 10 <sup>-4</sup>	$V_{CE} = 10V, I_C = 1.0mA,$ f = 1.0kHz	
Small Signal Current Gain	h <sub>fe</sub>	100	400			
Output Admittance	h <sub>oe</sub>	3.0	60	μS		
Current Gain-Bandwidth Product	f <sub>T</sub>	300	_	MHz	$V_{CE} = -20V, I_C = -10mA,$ f = 100MHz	
SWITCHING CHARACTERISTICS						
Delay Time	t <sub>d</sub>	_	35	ns	$V_{CC} = -3.0V, I_{C} = -10mA,$	
Rise Time	tr		35	ns	$V_{BE(off)} = 0.5V, I_{B1} = -1.0mA$	
Storage Time	ts	_	225	ns	$V_{CC} = -3.0V, I_{C} = -10mA,$	
Fall Time	t <sub>f</sub>		75	ns	$I_{B1} = I_{B2} = -1.0 \text{mA}$	

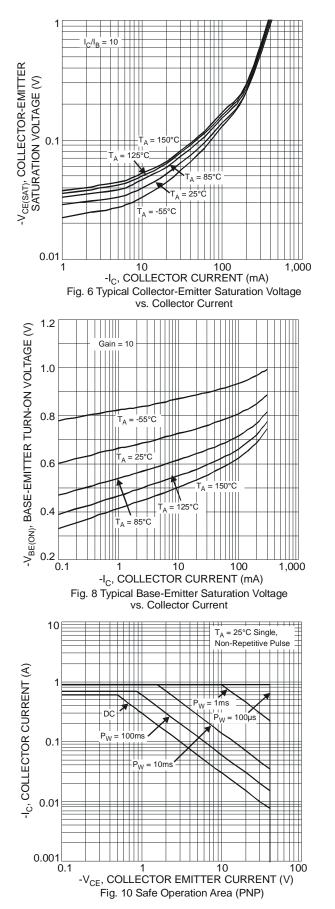
Notes: 4. Short duration pulse test used to minimize self-heating effect.

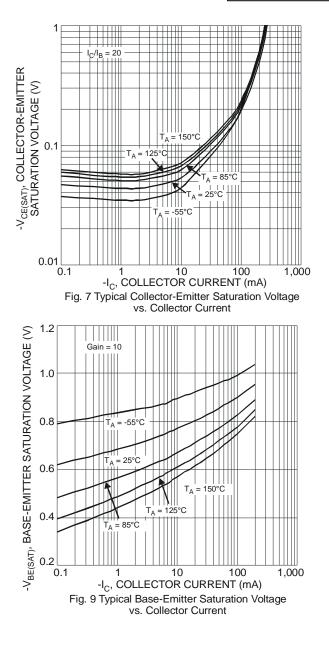












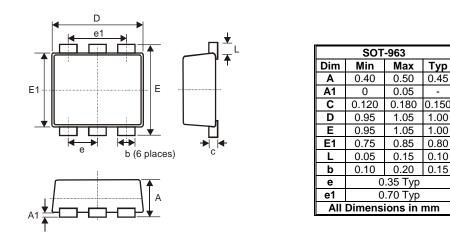


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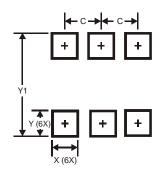
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# **Package Outline Dimensions**



# Suggest Pad Layout



Dimensions	Value (in mm)
С	0.350
Х	0.200
Y	0.200
Y1	1.100



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